

## 250-mA Ultra Low-Noise LDO Regulator With Error Flag and Discharge Option

### DESCRIPTION

The SiP21104 is a 250 mA CMOS LDO (low dropout) voltage regulator. It is the perfect choice for low voltage, low power applications. An ultra low ground current makes this part attractive for battery operated power systems. The SiP21104 also offers ultra low dropout voltage to prolong battery life in portable electronics. Systems requiring a quiet voltage source, such as RF applications, will benefit from the SiP21104's low output noise. The SiP21104 is designed to maintain regulation while delivering 400 mA peak current, making it ideal for systems that have a high surge current upon turn-on.

For better transient response and regulation, an active pull-down circuit is built into the SiP21104 to clamp the output voltage when it rises beyond normal regulation. The SiP21104 automatically discharges the output voltage by connecting the output to ground through a 100  $\Omega$  N-channel MOSFET when the device is put in shutdown mode.

The SiP21104 features reverse battery protection to limit reverse current flow to approximately 1  $\mu$ A in the event reversed battery is applied at the input, thus preventing damage to the IC.

The SiP21104 is available in a lead (Pb)-free 5-pin MLP22 PowerPAK package and is specified to operate over the industrial temperature range of - 40  $^{\circ}$ C to 85  $^{\circ}$ C.

### FEATURES

- Ultra low dropout - 250 mV at 250 mA load
- Low noise - 75  $\mu$ V<sub>RMS</sub> (10 Hz to 100 kHz)
- Shutdown control
- 130  $\mu$ A ground current at 250 mA load
- 2 % guaranteed output voltage accuracy
- 400 mA peak output current capability
- Uses low ESR ceramic capacitors
- Fast start-up (50  $\mu$ s)
- Fast line and load transient response ( $\leq$  30  $\mu$ s)
- 1  $\mu$ A maximum shutdown current
- Output current limit
- Reverse battery protection
- Built-in short circuit and thermal protection
- Out-of-regulation error flag (POWER<sub>GOOD</sub>)
- Output, auto-discharge in shutdown mode
- Fixed 1.2 V, 1.8 V, 2.5 V, 2.6 V, 2.8 V, 2.85 V, 3.0 V, 3.3 V, 5.0 V output voltage options
- MLP22-5 PowerPAK<sup>®</sup> package
- Compliant to RoHS directive 2002/95/EC

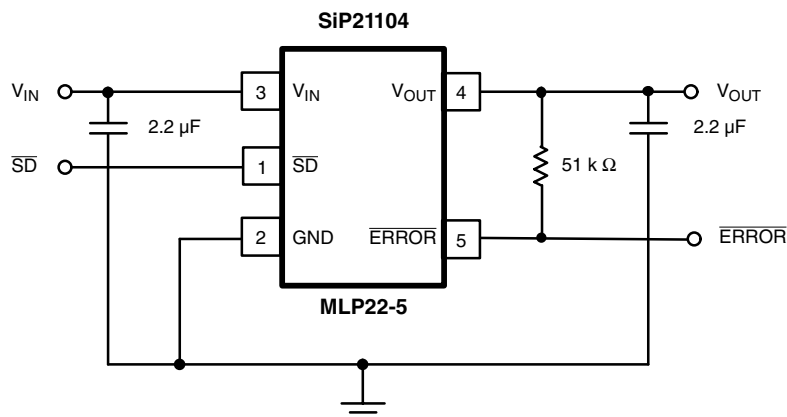


**RoHS\***  
COMPLIANT

### APPLICATIONS

- Cellular phones, wireless handsets
- Noise-sensitive electronic systems, laptop and palmtop computers
- PDAs
- Pagers
- Digital cameras
- MP3 player
- Wireless modem

### TYPICAL APPLICATION CIRCUIT



\* Pb containing terminations are not RoHS compliant, exemptions may apply .

### ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit	
Input Voltage, $V_{IN}$ to GND	- 6.0 to 6.5	V	
$V_{ERROR}$ , $V_{SD}$ (See Detailed Description)	- 0.3 to $V_{IN}$		
Output Current, $I_{OUT}$	Short Circuit Protected		
Output Voltage, $V_{OUT}$	- 0.3 to $V_{IN} + 0.3$	V	
Package Power Dissipation, $(P_d)^b$	1.23	W	
Thermal Resistance	$(Q_{JA})^a$	65	°C/W
	$R_{(QJC)}^a$	8	
Maximum Junction Temperature, $T_{J(max)}$	150	°C	
Storage Temperature, $T_{STG}$	- 65 to 150		

Notes:

- a. Device mounted with all leads soldered or welded to PC board.  
 b. Derate 15.4 mW/°C above  $T_A = 70$  °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### RECOMMENDED OPERATING RANGE

Parameter	Limit	Unit
Input Voltage, $V_{IN}$	2 to 6	V
Input Voltage, $V_{SD}$	0 to $V_{IN}$	
Output Current	0 to 250	mA
$C_{IN}$ , $C_{OUT}^a$ (Ceramic)	2.2	μF
$C_{EB}$ (Ceramic)	0.01	
Operating Ambient Temperature, $T_A$	- 40 to 85	°C
Operating Junction Temperature, $T_J$	- 40 to 125	

Notes:

- a. Maximum ESR of  $C_{OUT}$ : 0.2 Ω.

### SPECIFICATIONS

Parameter	Symbol	Test Conditions Unless Specified $T_A = 25$ °C, $V_{IN} = V_{OUT(nom)} + 1$ V, $I_{OUT} = 1$ mA, $C_{IN} = 2.2$ μF, $C_{OUT} = 2.2$ μF, $V_{SD} = 1.5$ V	Temp. <sup>a</sup>	Limits - 40 °C to 85 °C			Unit	
				Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>		
Input Voltage Range	$V_{IN}$		Full	2		6	V	
Output Voltage Accuracy		$1 \text{ mA} \leq I_{OUT} \leq 250 \text{ mA}$	$V_{OUT} \geq 1.8 \text{ V}$	Room	- 2.0	1	2.0	%
				Full	- 3.0	1	3.0	
			$V_{OUT} = 1.2 \text{ V}, 1.5 \text{ V}$	Room	- 2.5	1	2.5	
				Full	- 3.5	1	3.5	
Line Regulation ( $V_{OUT} \leq 3 \text{ V}$ )	$\frac{\Delta V_{OUT} \times 100}{\Delta V_{IN} \times V_{OUT(nom)}}$	From $V_{IN} = V_{OUT(nom)} + 1 \text{ V}$ to $V_{OUT(nom)} + 2 \text{ V}$	Full	- 0.06		0.18	%V	
Line Regulation ( $3.0 \text{ V} < V_{OUT} \leq 3.6 \text{ V}$ )			Full	0		0.3		
Line Regulation (5 V Version)			Full	0		0.4		
Dropout Voltage <sup>d, g</sup> ( $V_{OUT(nom)} \geq 2.6 \text{ V}$ )	$V_{IN} - V_{OUT}$	$I_{OUT} = 1 \text{ mA}$	Room		1		mV	
			Room		45	80		
				Full		50		90
			Room		250	350		
Full				415				
Dropout Voltage <sup>d, g</sup> ( $V_{OUT(nom)} < 2.6 \text{ V}, V_{IN} \geq 2 \text{ V}$ )		$I_{OUT} = 50 \text{ mA}$	Room		65	100		
			Full			120		
			Room		350	520		
	Full				570			

SPECIFICATIONS							
Parameter	Symbol	Test Conditions Unless Specified $T_A = 25\text{ }^\circ\text{C}$ , $V_{IN} = V_{OUT(nom)} + 1\text{ V}$ , $I_{OUT} = 1\text{ mA}$ , $C_{IN} = 2\text{ }\mu\text{F}$ , $C_{OUT} = 2.0\text{ }\mu\text{F}$ , $V_{SD} = 1.5\text{ V}$	Temp. <sup>a</sup>	Limits - 40 °C to 85 °C			Unit
				Min. <sup>b</sup>	Typ. <sup>c</sup>	Max. <sup>b</sup>	
Ground Pin Current <sup>e, 9</sup> ( $V_{OUT(nom)} \leq 3\text{ V}$ )	$I_{GND}$	$I_{OUT} = 0\text{ mA}$	Room		100	150	$\mu\text{A}$
			Full			180	
		$I_{OUT} = 250\text{ mA}$	Room		120	200	
			Full			330	
Ground Pin Current <sup>e, 9</sup> ( $V_{OUT(nom)} > 3\text{ V}$ )	$I_{GND}$	$I_{OUT} = 0\text{ mA}$	Room		110	170	$\mu\text{A}$
			Full			200	
		$I_{OUT} = 250\text{ mA}$	Room		150	225	
			Full			275	
Peak Output current	$I_{O(peak)}$	$V_{OUT} \geq 0.95 \times V_{OUT(nom)}$ ; $t_{PW} = 2\text{ ms}$	Full	400			mA
Output Noise Voltage	$e_N$	$V_{NOM} = 2.6\text{ V}$ , $BW = 10\text{ Hz to }100\text{ kHz}$ , $0\text{ mA} < I_{OUT} < 250\text{ mA}$ , $C_{NOISE} = 0.01\text{ }\mu\text{F}$	Room		75		$\mu\text{V(rms)}$
Ripple Rejection	$\Delta V_{OUT}/\Delta V_{IN}$	$I_{OUT} = 250\text{ mA}$	f = 1 kHz	Room	60		dB
			f = 10 kHz	Room	40		
			f = 100 kHz	Room	30		
Dynamic Line Regulation	$\Delta V_{O(line)}$	$V_{IN} : V_{OUT(nom)} + 1\text{ V to }V_{OUT(nom)} + 2\text{ V}$ $t_r/t_f = 2\text{ }\mu\text{s}$ , $I_{OUT} = 250\text{ mA}$	Room		20		mV
Dynamic Load Regulation	$\Delta V_{O(load)}$	$I_{OUT} : 1\text{ mA to }250\text{ mA}$ , $t_r/t_f = 2\text{ }\mu\text{s}$	Room		20		
Thermal Shutdown Junction Temperature	$T_{J(S/D)}$		Room		150		°C
Thermal Hysteresis	$T_{HYST}$		Room		20		
Reverse current	$I_R$	$V_{IN} = -6.0\text{ V}$	Room		1		$\mu\text{A}$
Short Circuit Current	$I_{SC}$	$V_{OUT} = 0\text{ V}$	Room		700		mA
<b>Shutdown</b>							
Shutdown Supply Current	$I_{CC(off)}$	$V_{SD} = 0\text{ V}$	Room		0.1	1	$\mu\text{A}$
$\overline{SD}$ Pin Input Voltage	$V_{SD}$	High = Regulator ON (Rising)	Full	1.5		$V_{IN}$	V
		Low = Regulator OFF (Falling)	Full			0.4	
Auto Discharge Resistance	$R_{DIS}$		Room		100		$\Omega$
$\overline{SD}$ Pin Input Current <sup>f</sup>	$I_{IN(\overline{SD})}$	$V_{SD} = 1.5\text{ V}$ , $V_{IN} = 6\text{ V}$	Room		0.7		$\mu\text{A}$
$\overline{SD}$ Hysteresis	$V_{HYST(\overline{SD})}$		Full		150		mV
$V_{OUT}$ Turn-On Time	$t_{ON}$	$V_{SD}$ (See Figure 1), $I_{LOAD} = 100\text{ nA}$			50		$\mu\text{s}$
<b>ERROR Output</b>							
ERROR High Leakage	$I_{OFF}$	$\overline{ERROR} \leq V_{IN}$ . $V_{OUT}$ in Regulation	Full			1	$\mu\text{A}$
ERROR Low Voltage	$V_{OL}$	$I_{SINK} = 0.5\text{ mA}$	Full			0.4	V
ERROR Voltage Threshold	$V_{\overline{ERROR}}$	$V_{OUT}$ Below $V_{OUT(nom)}$ <sup>g</sup> , $V_{IN} \geq 2\text{ V}$ $V_{OUT}$ Falling, $I_{OUT} = 1\text{ mA}$ , $V_{OUT(nom)} \geq 2\text{ V}$	Full	- 2	- 4	- 6	%
		$V_{OUT(nom)}$ <sup>g</sup> < 2 V, $V_{IN} > 2\text{ V}$	Full		- 4		
ERROR Voltage Threshold Hysteresis	$V_{HYST(\overline{ERROR})}$		Room		1.5		

Notes:

- Room = 25 °C, Full = - 40 °C to 85 °C.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing. Typical values for dropout voltage at  $V_{OUT} \geq 2\text{ V}$  are measured at  $V_{OUT} = 3.3\text{ V}$ , while typical values for dropout voltage at  $V_{OUT} < 2\text{ V}$  are measured at  $V_{OUT} = 1.8\text{ V}$ .
- Dropout voltage is defined as the input to output differential voltage at which the output voltage drops 2 % below the output voltage measured with a 1 V differential, provided that  $V_{IN}$  does not drop below 2.0 V.
- Ground current is specified for normal operation as well as “drop-out” operation.
- The device’s shutdown pin includes a typical 2 M $\Omega$  internal pull-down resistor connected to ground.
- $V_{OUT(nom)}$  is  $V_{OUT}$  when measured with a 1 V differential to  $V_{IN}$ .

## TIMING WAVEFORMS

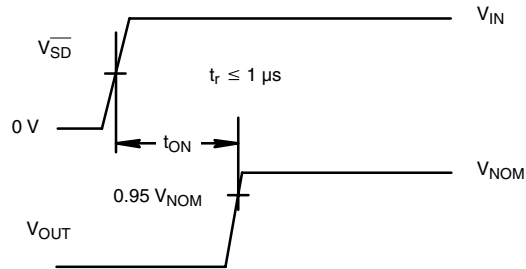
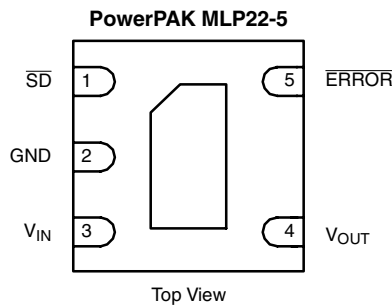


Figure 1. Timing Diagram for Power-Up

## PIN CONFIGURATION



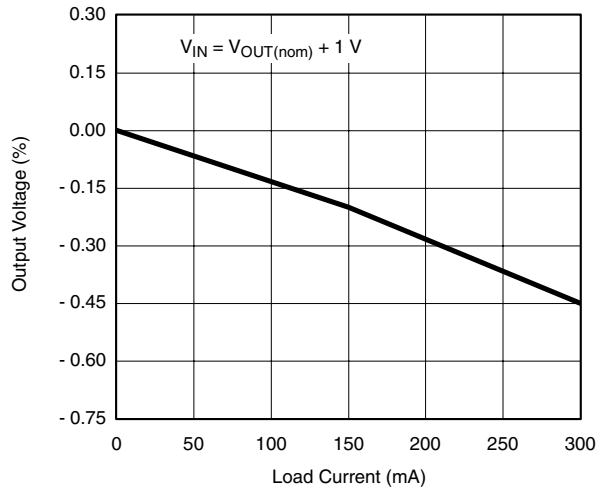
### PIN DESCRIPTION

Pin Number	Name	Function
1	$\overline{SD}$	By applying less than 0.4 V to this pin, the device will be turned off. Connect this pin to $V_{IN}$ if unused
2	GND	Ground pin. For better thermal capability, directly connected to large ground plane
3	$V_{IN}$	Input supply pin. Bypass this pin with a 1 $\mu F$ ceramic or tantalum capacitor to ground
4	$V_{OUT}$	Output voltage. Connect $C_{OUT}$ between this pin and ground.
5	$\overline{ERROR}$	The open drain output is an error flag output which goes low when $V_{OUT}$ drops 4 % below its nominal value.

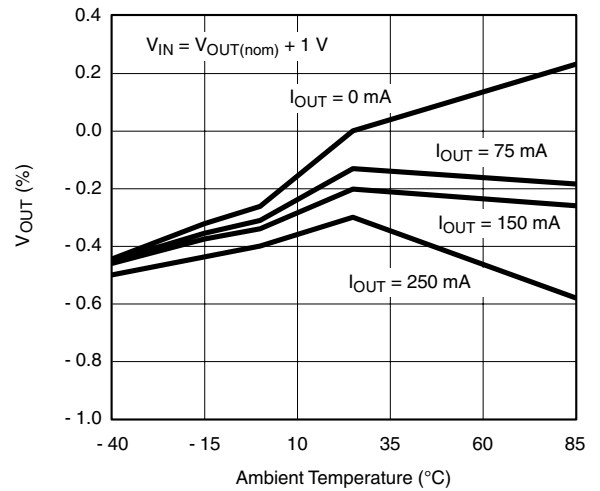
### ORDERING INFORMATION

Lead (Pb)-free Part Number	Marking	Voltage	Temperature Range	Package
SiP21104DLP-12-E3	Y0LL	1.2	- 40 °C to 85 °C	MLP22-5
SiP21104DLP-18-E3	E0LL	1.8		
SiP21104DLP-25-E3	E3LL	2.5		
SiP21104DLP-26-E3	E4LL	2.6		
SiP21104DLP-28-E3	E6LL	2.8		
SiP21104DLP-285-E3	A7LL	2.85		
SiP21104DLP-30-E3	E9LL	3.0		
SiP21104DLP-33-E3	F0LL	3.3		
SiP21104DLP-50-E3	F3LL	5.0		

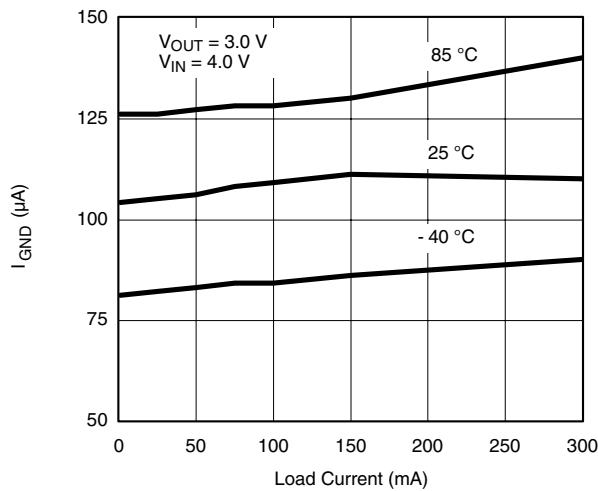
**TYPICAL CHARACTERISTICS** Internally Regulated, 25 °C, unless otherwise noted



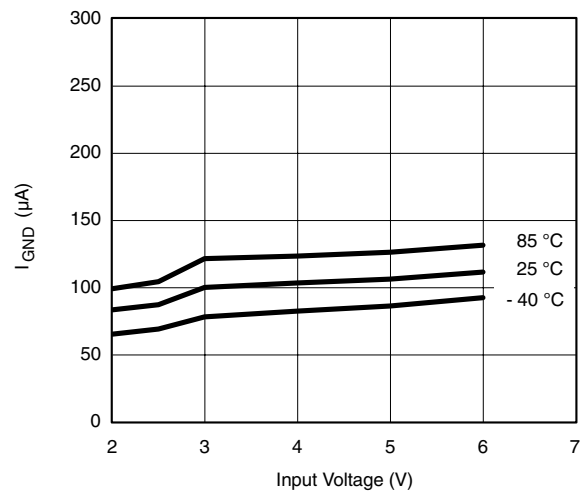
**Normalized Output Voltage vs. Load Current**



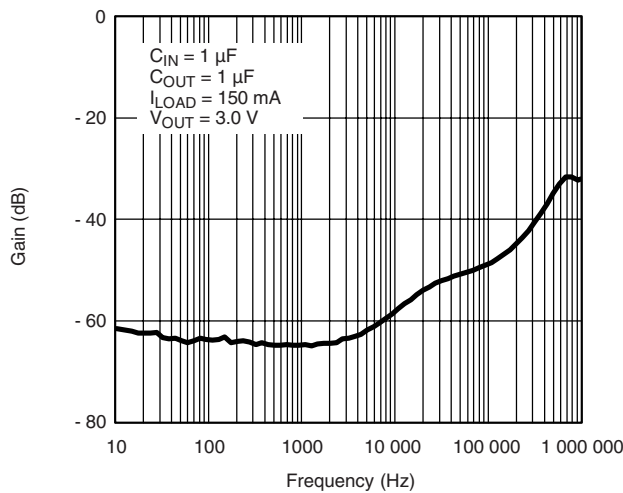
**Normalized  $V_{OUT}$  vs. Temperature**



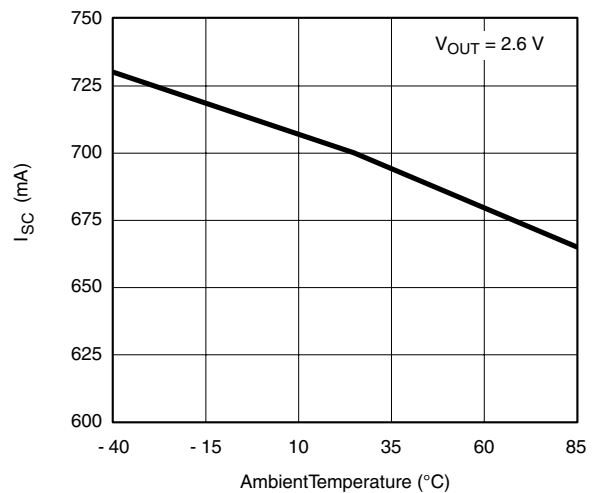
**GND Current vs. Load Current**



**No Load GND Pin Current vs. Input Voltage**

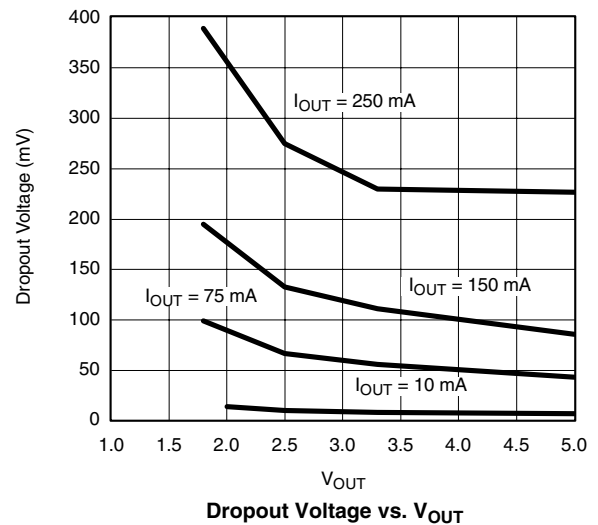
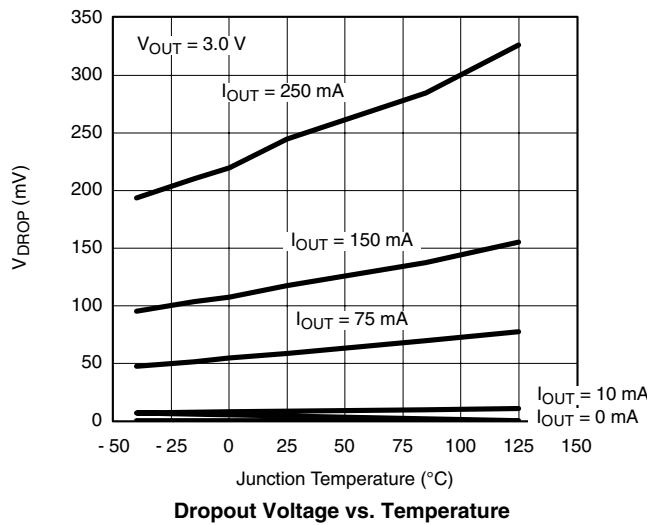
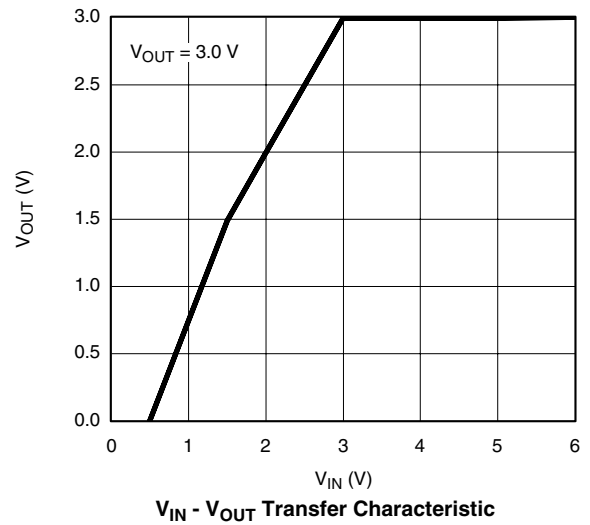
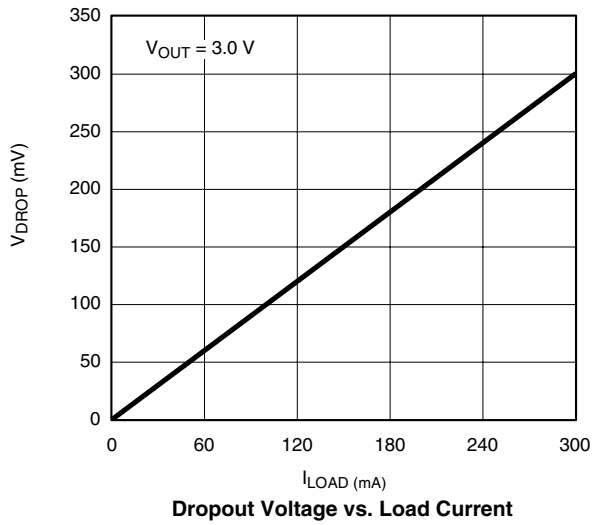


**Power Supply Rejection**

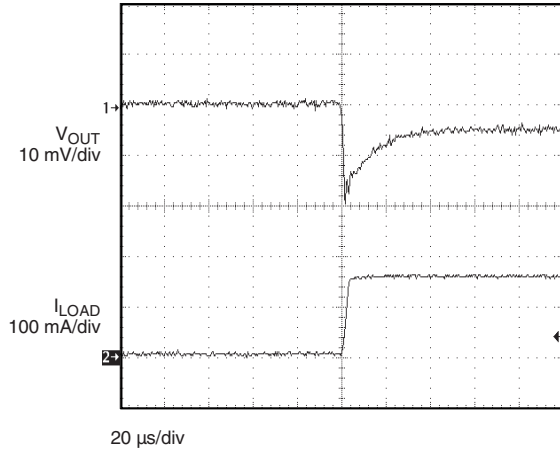


**Output Short Circuit Current vs. Temperature**

**TYPICAL CHARACTERISTICS** Internally Regulated, 25 °C, unless otherwise noted

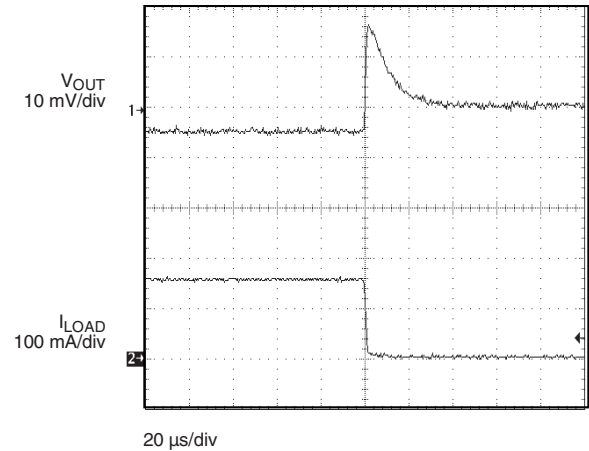


**TYPICAL WAVEFORMS**



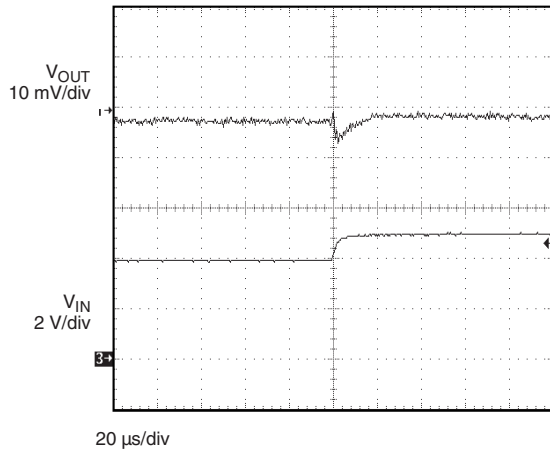
$V_{OUT} = 3.0\text{ V}$   
 $C_{OUT} = 10\ \mu\text{F}$   
 $I_{LOAD} = 1\text{ to }150\text{ mA}$   
 $t_{rise} = 2\ \mu\text{s}$

**Load Transient Response-1**



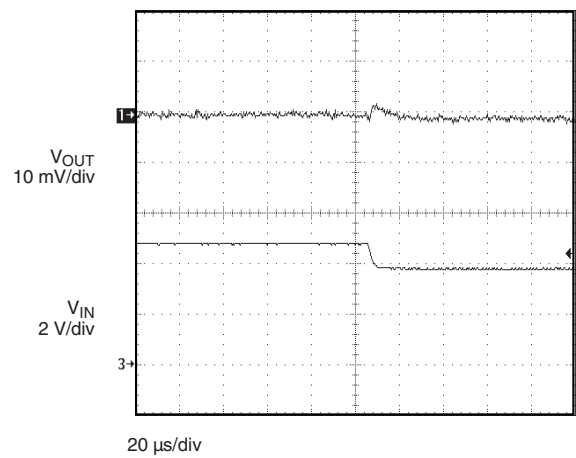
$V_{OUT} = 3.0\text{ V}$   
 $C_{OUT} = 10\ \mu\text{F}$   
 $I_{LOAD} = 150\text{ to }1\text{ mA}$   
 $t_{fall} = 2\ \mu\text{s}$

**Load Transient Response-2**



$V_{INSTEP} = 4\text{ to }5\text{ V}$   
 $V_{OUT} = 3\text{ V}$   
 $C_{OUT} = 1\ \mu\text{F}$   
 $C_{IN} = 1\ \mu\text{F}$   
 $I_{LOAD} = 150\text{ mA}$   
 $t_{rise} = 5\ \mu\text{s}$

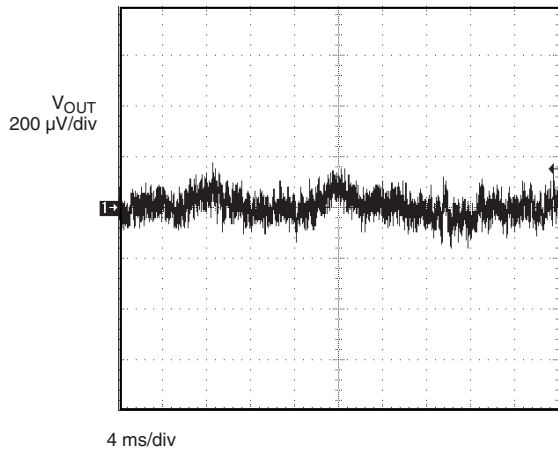
**Line Transient Response-1**



$V_{INSTEP} = 5\text{ to }4\text{ V}$   
 $V_{OUT} = 3\text{ V}$   
 $C_{OUT} = 1\ \mu\text{F}$   
 $C_{IN} = 1\ \mu\text{F}$   
 $I_{LOAD} = 150\text{ mA}$   
 $t_{fall} = 5\ \mu\text{s}$

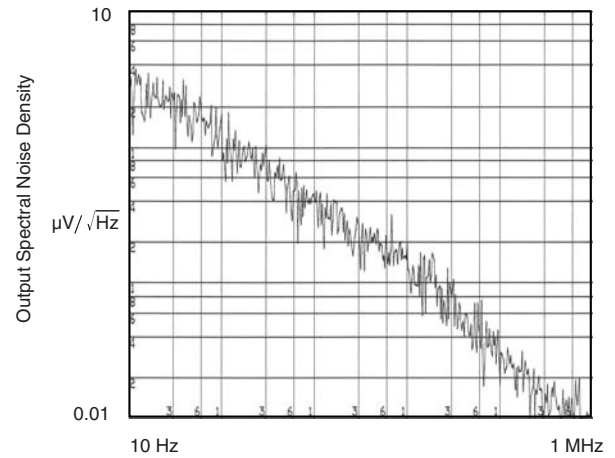
**Line Transient Response-2**

## TYPICAL WAVEFORMS



$V_{IN} = 4\text{ V}$   
 $V_{OUT} = 3\text{ V}$   
 $I_{OUT} = 150\text{ mA}$   
 $C_{NOISE} = 0.01\text{ }\mu\text{F}$   
 $BW = 10\text{ Hz to }100\text{ kHz}$

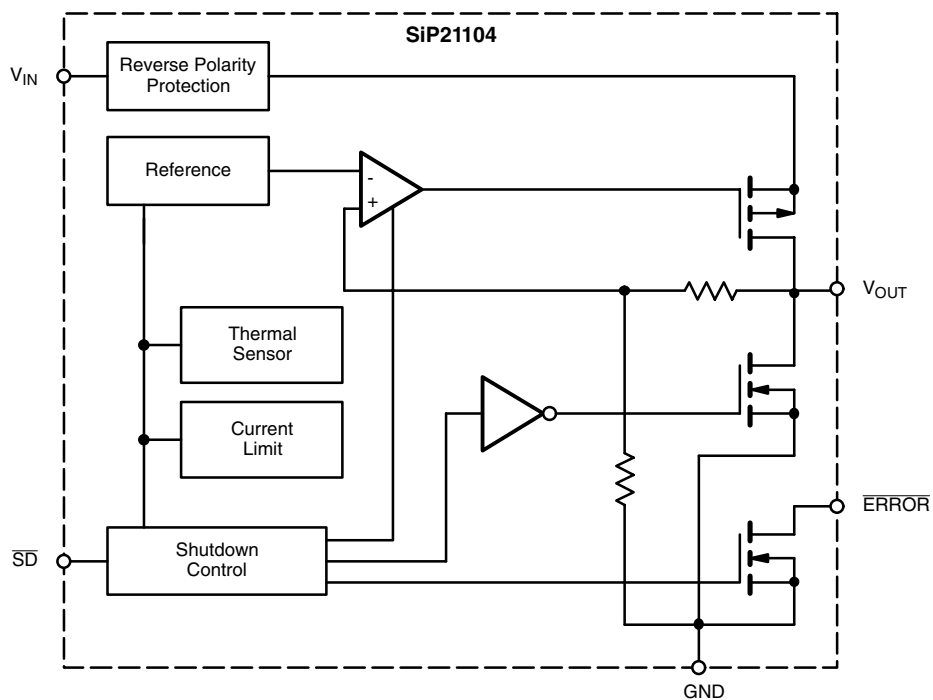
**Output Noise**



$V_{IN} = 4\text{ V}$   
 $V_{OUT} = 3\text{ V}$   
 $I_{LOAD} = 150\text{ mA}$   
 $C_{NOISE} = 0.01\text{ }\mu\text{F}$

**Noise Spectrum**

## FUNCTIONAL BLOCK DIAGRAM





## DETAILED DESCRIPTION

The SiP21104 is a low-noise, low drop-out and low quiescent current linear voltage regulator, packaged in a small footprint MLP22-5 package. The SiP21104 can supply loads up to 250 mA. As shown in the block diagram, the circuit consists of a bandgap reference error, amplifier, P-channel pass transistor and feedback resistor string. Additional blocks, not shown in the block diagram, include a precise current limiter, reverse battery and current protection and thermal sensor.

### Thermal Overload Protection

The thermal overload protection limits the total power dissipation and protects the device from being damaged. When the junction temperature exceeds 150 °C, the device turns the P-Channel pass transistor off.

### Reverse Battery Protection

The SiP21104 has a battery reverse protection circuitry that disconnects the internal circuitry when  $V_{IN}$  drops below the GND voltage. There is no current drawn in such an event. When the  $\overline{SD}$  pin is hardwired to  $V_{IN}$ , the user must connect the  $\overline{SD}$  pin to  $V_{IN}$  via a 100 k $\Omega$  resistor if reverse battery protection is desired. Hardwiring the  $\overline{SD}$  pin directly to the  $V_{IN}$  pin is allowed when reverse battery protection is not desired.

### ERROR

ERROR is an open drain output that goes low when  $V_{OUT}$  is less than 4 % of its normal value. To obtain a logic level output, connect a pull-up resistor from  $\overline{ERROR}$  to  $V_{OUT}$  or any other voltage equal to or less than  $V_{IN}$ .  $\overline{ERROR}$  pin is high impedance (off) when  $\overline{SD}$  pin is low.

### Auto-Discharge

The SiP21104  $V_{OUT}$  has an internal 100  $\Omega$  (typ.) discharge path to ground when the  $\overline{SD}$  pin is low.

### Stability

The circuit is stable with only a small output capacitor equal to 6 nF/mA (= 1.5  $\mu$ F at 250 mA). Since the bandwidth of the error amplifier is around 1-3 MHz and the dominant pole is at

the output node, the capacitor should be capacitive in this range, i.e., for 250 mA load current, an ESR < 0.2  $\Omega$  is necessary. Parasitic inductance of about 10 nH can be tolerated.

### Safe Operating Area

The ability of the SiP21104 to supply current is ultimately dependent on the junction temperature of the pass device. Junction temperature is in turn dependent on power dissipation in the pass device, the thermal resistance of the package and the circuit board, and the ambient temperature. The power dissipation is defined as

$$P_D = (V_{IN} - V_{OUT}) * I_{OUT}$$

Junction temperature is defined as

$$T_J = T_A + (P_D * (R_{\theta_{JC}} + R_{\theta_{CA}}))$$

To calculate the limits of performance, these equations must be rewritten.

Allowable power dissipation is calculated using the equation

$$P_D = (T_J - T_A) / (R_{\theta_{JC}} + R_{\theta_{CA}})$$

While allowable output current is calculated using the equation

$$I_{OUT} = (T_J - T_A) / (R_{\theta_{JC}} + R_{\theta_{CA}}) * (V_{IN} - V_{OUT})$$

Ratings of the SiP21104 that must be observed are

$$T_{Jmax} = 150 \text{ }^\circ\text{C}, T_{Amax} = 85 \text{ }^\circ\text{C}, (V_{IN} - V_{OUT})_{max} = 5.3 \text{ V}, R_{\theta_{JC}} = 8 \text{ }^\circ\text{C/W}$$

The value of  $R_{\theta_{CA}}$  is dependent on the PC board used. The value of  $R_{\theta_{CA}}$  for the board used in device characterization is approximately 57  $^\circ\text{C/W}$ .

Figure 1 shows the performance limits graphically for the SiP21104 mounted on the circuit board used for thermal characterization.



## Disclaimer

All product specifications and data are subject to change without notice.

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